# VS-85HF(R) 40M8

**Vishay Semiconductors** 



### Standard Recovery Diodes, (Stud Version), 85 A



DO-5 (DO-203AB)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 85 A					
Package	DO-5 (DO-203AB)				
Circuit configuration	Single				

#### FEATURES

- High surge current capability
- · Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V<sub>RBM</sub>
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS						
DADAMETED	TEST CONDITIONS	85HF(R)				
PARAMETER	TEST CONDITIONS	400	– UNITS			
1		85	А			
I <sub>F(AV)</sub>	T <sub>C</sub>	140	°C			
I <sub>F(RMS)</sub>		133	A			
I <sub>FSM</sub>	50 Hz	1700	٨			
	60 Hz	1800	A			
l <sup>2</sup> t	50 Hz	14 500	A2-			
14	60 Hz	13 500	A <sup>2</sup> s			
V <sub>RRM</sub>		400	V			
TJ		-65 to +180	٥C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA				
VS-85HF(R)	40	400	500	9				



## VS-85HF(R) 40M8



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PARAMETER	SYMBOL	TEST CONDITIONS			85HF(R)	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	180° conduction, half sine wave			85 140	A
at case temperature	1((1))					°C
Maximum RMS forward current	I <sub>F(RMS)</sub>			133	A	
		t = 10 ms	No voltage		1700	- A
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1800	
non-repetitive surge current	IFSM	t = 10 ms	100 % V <sub>RRM</sub>		1450	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1500	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	14 500	A <sup>2</sup> s
	l <sup>2</sup> t	t = 8.3 ms	reapplied		13 500	
	1-1	t = 10 ms	100 % V <sub>RRM</sub>		10 500	
		t = 8.3 ms	reapplied		9400	
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	16 000	A²√s
Value of threshold voltage (up to 1200 V)	N	T <sub>J</sub> = T <sub>J</sub> maximum			0.68	v
Value of threshold voltage (for 1400 V, 1600 V)	V <sub>F(TO)</sub>				0.69	v
Value of forward slope resistance (up to 1200 V)		T <sub>J</sub> = T <sub>J</sub> maximum			1.62	
Value of forward slope resistance (for 1400 V, 1600 V)	r <sub>f</sub>				1.75	- mW
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk}$ = 267 A, $T_J$ = 25 °C, $t_p$ = 400 µs rectangular wave			1.2	V

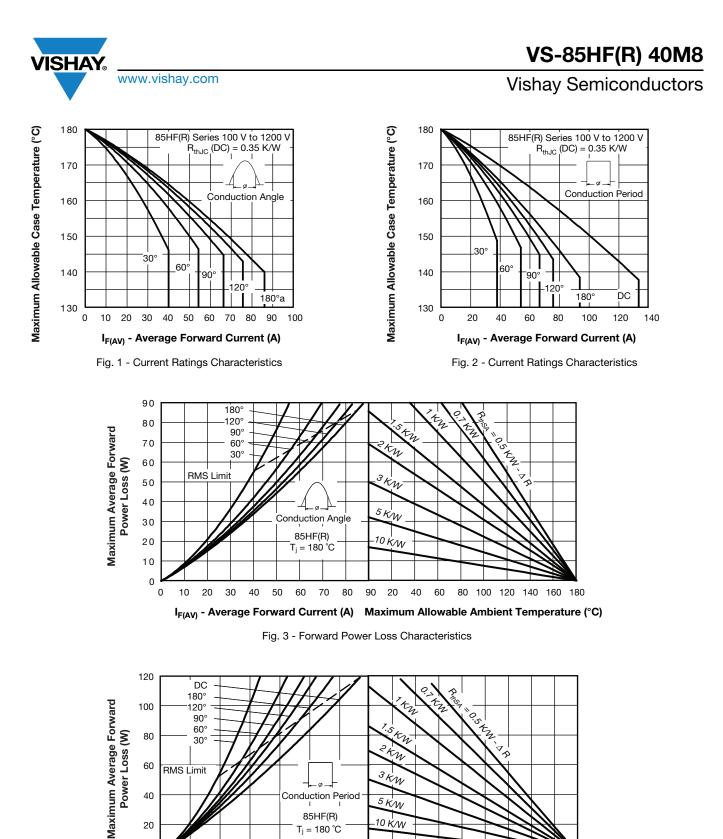
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	85HF(R)	UNITS		
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +180	°C		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	0.35	K/W		
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.25	r\/ vv		
Maximum shock			1500			
Maximum constant vibration		50 Hz	20	g		
Maximum constant acceleration		Stud outwards	5000			
		Not lubricated thread, tighting on nut	3.4 (30)			
Maximum allowable mounting torque		Lubricated thread, tighting on nut	2.3 (20)	N·m		
+0 %, -10 %		Not lubricated thread, tighting on hexagon	4.2 (37)	(lbf · in)		
		Lubricated thread, tighting on hexagon	3.2 (28)			
Approvimeto weight		Unleaded device	17	g		
Approximate weight		Unleaded device	0.6	oz.		
Case style		See dimensions - link at the end of datasheet	DO-5 (DO-	203AB)		

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.10	0.08				
120°	0.11	0.11				
90°	0.13	0.13	$T_J = T_J maximum$	K/W		
60°	0.17	0.17				
30°	0.26	0.26				

Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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85HF(R)

T<sub>j</sub> = 180 °C

100

120 140

20

0

0

20

40

60

80

Fig. 4 - Forward Power Loss Characteristics

10 k⁄w

20 40 60

I<sub>F(AV)</sub> - Average Forward Current (A) Maximum Allowable Ambient Temperature (°C)

80 100 120 140 160 180

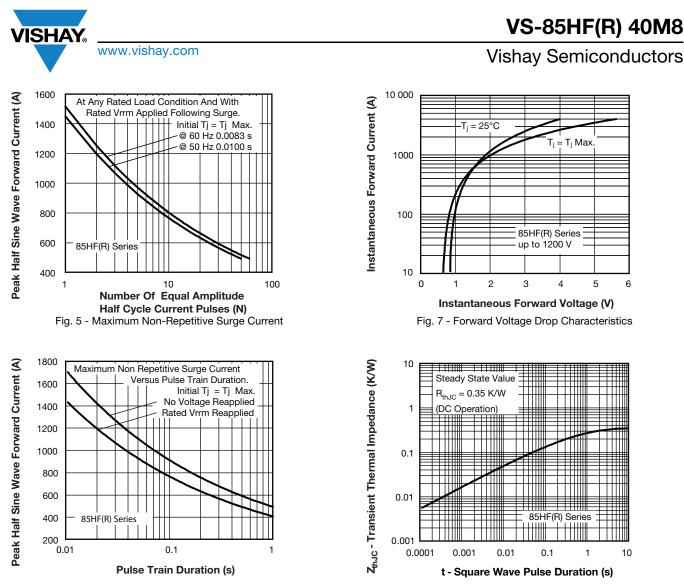
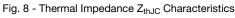


Fig. 6 - Maximum Non-Repetitive Surge Current



### **ORDERING INFORMATION TABLE**

Device code	vs-	85	HF	R	40	M8
	1	2	3	4	5	6
	1 -	Vis	hay Sen	nicondu	ctors pro	oduct
	2 -	85 =	= standa	rd devid	e	
	3 -	HF	= standa	ard diod	е	
	4 -	Non	ie = stud	d norma	l polarity	(catho
	_			-	larity (a	
	5 -		-		= V <sub>RRM</sub> (	
	6 -	M8	= stud b	ase DO	-5 (DO-2	203AB)

LINKS TO RELATED DOCUMENTS					
Dimensions	WV	ww.vishay.com/doc?95342			
Revision: 11-Jan-18	4	Document Number: 93529			
For technical questions within your r	egion: DiodesAmericas@vishav.com, DiodesAsia@	vishav.com_DiodesEurope@vishav.com			

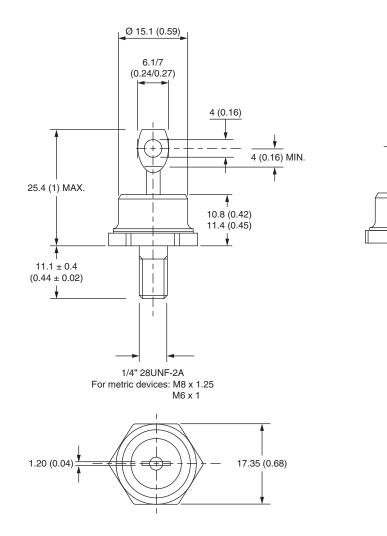
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# DO-5 (DO-203AB) for 85HF(R), 86HF(R) and 88HF(R)Series

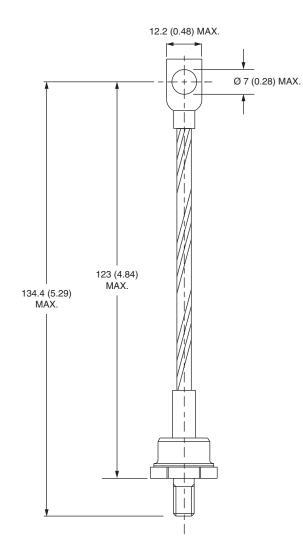
### DIMENSIONS FOR 85HF(R) SERIES in millimeters (inches)





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#### DIMENSIONS FOR 86HF(R) SERIES in millimeters (inches)

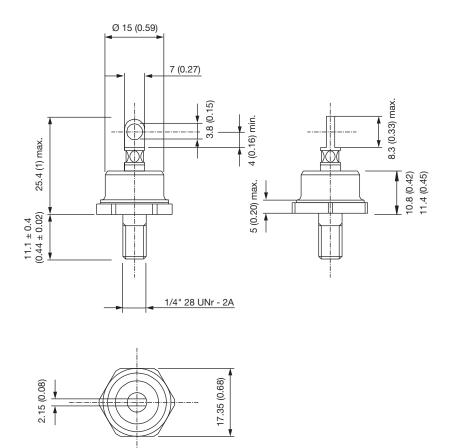


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#### DIMENSIONS 88HF(R) SERIES in millimeters (inches)





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